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# **Analog Multiplexers / Demultiplexers**

The MC14067 multiplexer/demultiplexer is a digitally controlled analog switch featuring low ON resistance and very low leakage current. This device can be used in either digital or analog applications.

The MC14067 is a 16-channel multiplexer/demultiplexer with an inhibit and four binary control inputs A, B, C, and D. These control inputs select 1-of-16 channels by turning ON the appropriate analog switch (see MC14067 truth table.)

#### **Features**

- Low OFF Leakage Current
- Matched Channel Resistance
- Low Quiescent Power Consumption
- Low Crosstalk Between Channels
- Wide Operating Voltage Range: 3 to 18 V
- Low Noise
- Pin for Pin Replacement for CD4067B
- These Devices are Pb-Free and are RoHS Compliant
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

#### MAXIMUM RATINGS (Voltages Referenced to VSS)

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	DC Supply Voltage Range	- 0.5 to + 18.0	V
V <sub>in</sub> , V <sub>out</sub>	Input or Output Voltage Range (DC or Transient)	– 0.5 to V <sub>DD</sub> + 0.5	V
l <sub>in</sub>	Input Current (DC or Transient), per Control Pin	±10	mA
I <sub>sw</sub>	Switch Through Current	±25	mA
P <sub>D</sub>	Power Dissipation, per Package (Note 1)	500	mW
T <sub>A</sub>	Ambient Temperature Range	- 55 to + 125	°C
T <sub>stg</sub>	Storage Temperature Range	- 65 to + 150	°C
TL	Lead Temperature (8–Second Soldering)	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$ 

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.



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SOIC-24 DW SUFFIX CASE 751E

#### MARKING DIAGRAM

14067B

O AWLYYWWG

A = Assembly Location

WL = Wafer Lot

YY = Year

WW = Work Week

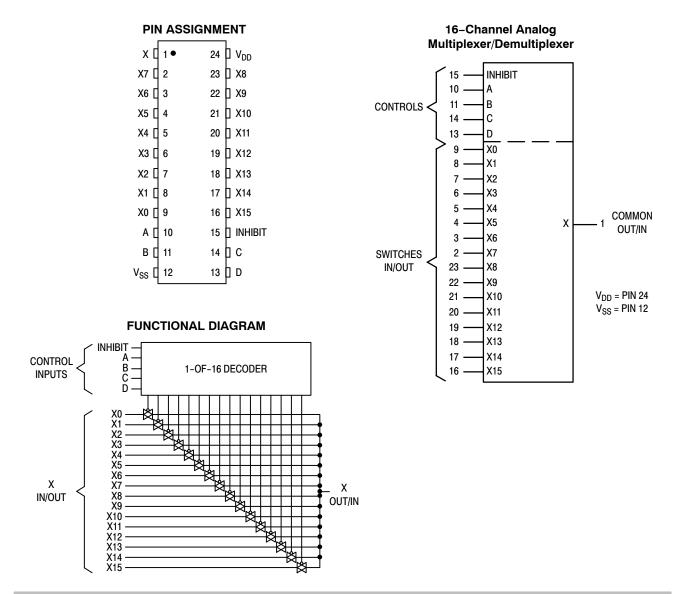
G = Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

**TRUTH TABLE** 

	Selected				
Α	В	С	D	Inh	Channel
Х	Х	X	Х	1	None
0	0	0	0	0	X0
1	0	0	0	0	X1
0	1	0	0	0	X2
1	1	0	0	0	Х3
0	0	1	0	0	X4
1	0	1	0	0	X5
0	1	1	0	0	X6
1	1	1	0	0	X7
0	0	0	1	0	X8
1	0	0	1	0	X9
0	1	0	1	0	X10
1	1	0	1	0	X11
0	0	1	1	0	X12
1	0	1	1	0	X13
0	1	1	1	0	X14
1	1	1	1	0	X15



#### **ELECTRICAL CHARACTERISTICS**

				– 55°C		25°C			125°C		]
Characteristic	Symbol	V <sub>DD</sub>	Test Conditions	Min	Max	Min	Typ <sup>(2)</sup>	Max	Min	Max	Unit
SUPPLY REQUIREMENTS	(Voltages	Refere	nced to V <sub>SS</sub> )			ı			ı		
Power Supply Voltage Range	V <sub>DD</sub>	-		3.0	18	3.0	-	18	3.0	18	V
Quiescent Current Per Package	I <sub>DD</sub>	5.0 10 15	$ \begin{array}{l} \text{Control Inputs: V}_{\text{in}} = \\ \text{V}_{\text{SS}} \text{ or V}_{\text{DD}}, \\ \text{Switch I/O: V}_{\text{SS}} \leq \text{V}_{\text{I/O}} \leq \\ \text{V}_{\text{DD}}, \text{ and} \\ \Delta \text{V}_{\text{switch}} \leq 500 \text{ mV} \end{array} $	- - -	5.0 10 20	- - -	0.005 0.010 0.015	5.0 10 20	- - -	150 300 600	μΑ
Total Supply Current I <sub>D(AV)</sub> 5.0 (Dynamic Plus Quiescent, Per Package			T <sub>A</sub> = 25°C only (The channel component, (V <sub>in</sub> – V <sub>out</sub> )/R <sub>on</sub> , is not included.)	(0.07 μA/kHz) f + I <sub>DD</sub> Typical (0.20 μA/kHz) f + I <sub>DD</sub> (0.36 μA/kHz) f + I <sub>DD</sub>					μΑ		
CONTROL INPUTS — INHI	IBIT, A, B,	C, D (\	/oltages Referenced to V <sub>SS</sub> )	1	1	1	1	1	1	1	ı
Low-Level Input Voltage	V <sub>IL</sub>	5.0 10 15	R <sub>on</sub> = per spec, I <sub>off</sub> = per spec	- - -	1.5 3.0 4.0	- - -	2.25 4.50 6.75	1.5 3.0 4.0	- - -	1.5 3.0 4.0	V
High-Level Input Voltage	V <sub>IH</sub>	5.0 10 15	R <sub>on</sub> = per spec, I <sub>off</sub> = per spec	3.5 7.0 11	- - -	3.5 7.0 11	2.75 5.50 8.25	- - -	3.5 7.0 11	- - -	٧
Input Leakage Current	l <sub>in</sub>	15	V <sub>in</sub> = 0 or V <sub>DD</sub>	-	± 0.1	-	±0.00001	± 0.1	_	1.0	μΑ
Input Capacitance	C <sub>in</sub>	_		-	-	-	5.0	7.5	-	-	pF
SWITCHES IN/OUT AND C	OMMONS	OUT/II	N — X, Y (Voltages Reference	ced to \	/ <sub>SS</sub> )	I			ı		
Recommended Peak-to- Peak Voltage Into or Out of the Switch	V <sub>I/O</sub>	_	Channel On or Off	0	V <sub>DD</sub>	0	-	V <sub>DD</sub>	0	V <sub>DD</sub>	V <sub>p-p</sub>
Recommended Static or Dynamic Voltage Across the Switch <sup>(3)</sup> (Figure 1)	$\Delta V_{switch}$	-	Channel On	0	600	0	-	600	0	300	mV
Output Offset Voltage	V <sub>OO</sub>	-	V <sub>in</sub> = 0 V, No Load	_	-	-	10	-	-	-	μV
ON Resistance	R <sub>on</sub>	5.0 10 15	$\begin{split} \Delta V_{switch} &\leq 500 \text{ mV }^{(3)}, \\ V_{in} &= V_{IL} \text{ or } V_{IH} \\ \text{ (Control), and } V_{in} \\ \text{ 0 to } V_{DD} \text{ (Switch)} \end{split}$	- - -	800 400 220	- - -	250 120 80	1050 500 280	- - -	1300 550 320	Ω
ΔON Resistance Between Any Two Channels in the Same Package	$\Delta R_{on}$	5.0 10 15		- - -	70 50 45	- - -	25 10 10	70 50 45	- - -	135 95 65	Ω
Off-Channel Leakage Current (Figure 2)	I <sub>off</sub>	15	V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub> (Control) Channel to Channel or Any One Channel	_	± 100	-	± 0.05	±100	-	±1000	nA
Capacitance, Switch I/O	C <sub>I/O</sub>	-	Inhibit = V <sub>DD</sub>	-	_	_	10	-	-	-	pF
Capacitance, Common O/I	C <sub>O/I</sub>	-	Inhibit = V <sub>DD</sub> (MC14067B) (MC14097B)	- -	- -	- -	100 60	- -	- -	- -	pF
Capacitance, Feedthrough (Channel Off)	C <sub>I/O</sub>	-	Pins Not Adjacent Pins Adjacent	_	-	-	0.47	-	-	-	pF

Data labeled "Typ" is not to be used for design purposes, but is intended as an indication of the IC's potential performance.
 For voltage drops across the switch (ΔV<sub>switch</sub>) > 600 mV ( > 300 mV at high temperature), excessive V<sub>DD</sub> current may be drawn; i.e. the current out of the switch may contain both V<sub>DD</sub> and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.)

## **ELECTRICAL CHARACTERISTICS** ( $C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$ )

Characteristic	Symbol	V <sub>DD</sub> - V <sub>SS</sub>	Тур (4)	Max	Unit
Propagation Delay Times Channel Input–to–Channel Output (R <sub>L</sub> = 200 k $\Omega$ )	t <sub>PLH</sub> , t <sub>PHL</sub>				ns
MC14067B	(Figure 3)	5.0	35	90	
		10 15	15 12	40 30	
Propagation Delay Times Channel Input-to-Channel Output ( $R_L$ = 1.0 k $\Omega$ )	t <sub>PLH</sub> , t <sub>PHL</sub>				ns
MC14067B	(Figure 3)	5.0		50	
		10 15		30 20	
Control Input-to-Channel Output					ns
Channel Turn–On Time ( $R_L$ = 10 k $\Omega$ ) MC14067B		5.0	240	600	
	l	10	115	290	
	t <sub>PZH</sub> , t <sub>PZL</sub>	15	75	190	
Channel Turn–Off Time (R <sub>L</sub> = 300 k $\Omega$ ) MC14067B	(Figure 4)				ns
		5.0	250	625	
	t <sub>PHZ</sub> , t <sub>PLZ</sub>	10 15	120 75	300 190	
Channel Turn–Off Time ( $R_L$ = 10 k $\Omega$ ) MC14067B	(Figure 4)				ns
		5.0		625	
		10 15		450 350	
Any Pair of Address Inputs to Output MC14067B	t <sub>PLH</sub> , t <sub>PHL</sub>				ns
		5.0	280	700	
		10 15	115 85	290 215	
Second Harmonic Distortion $(R_L = 10 \text{ k}\Omega, \text{ f} = 1 \text{ kHz}, \text{ V}_{\text{in}} = 5 \text{ V}_{\text{p-p}})$	_	10	0.3	-	%
ON Channel Bandwidth	BW				MHz
[R <sub>L</sub> = 50 $\Omega$ , V <sub>in</sub> = 1/2 (V <sub>DD</sub> - V <sub>SS</sub> ) <sub>p-p</sub> (sine-wave)] 20 Log10 (V <sub>out</sub> /V <sub>in</sub> ) = - 3 dB MC14067B	(Figure 5)	10	15	_	
Off Channel Feedthrough Attenuation	-	10	- 40	_	dB
[R <sub>L</sub> = 50 $\Omega$ , V <sub>in</sub> = 1/2 (V <sub>DD</sub> -V <sub>SS</sub> ) <sub>p-p</sub> (sine-wave)] $f_{in}$ = 20 MHz - MC14067B	(Figure 5)				
Channel Separation	_	10	- 40	-	dB
$[R_L = 1 \text{ k}\Omega, V_{in} = 1/2 \text{ (}V_{DD} \text{-}V_{SS}\text{) }_{p-p} \text{ (sine-wave)}]$ $f_{in} = 20 \text{ MHz}$	(Figure 6)				
Crosstalk, Control Inputs–to–Common O/I (R1 = 1 k $\Omega$ , R <sub>L</sub> = 10 k $\Omega$ ,	_	10	30	-	mV
Control $t_r = t_f = 20 \text{ ns}$ , Inhibit = $V_{SS}$ )	(Figure 7)				

<sup>4.</sup> Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>			
MC14067BDWG	SOIC-24	30 Units / Rail			
NLV14067BDWG*	(Pb-Free)				
MC14067BDWR2G	SOIC-24	1000 Units / Tape & Reel			
NLV14067BDWR2G*	(Pb-Free)				

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

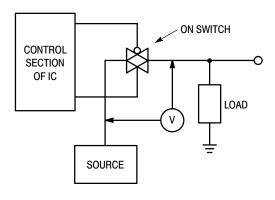


Figure 1.  $\Delta V$  Across Switch

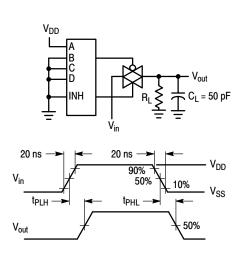


Figure 3. Propagation Delay Test Circuit and Waveforms V<sub>in</sub> to V<sub>out</sub>

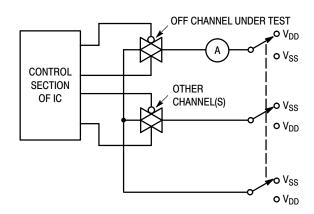


Figure 2. Off Channel Leakage

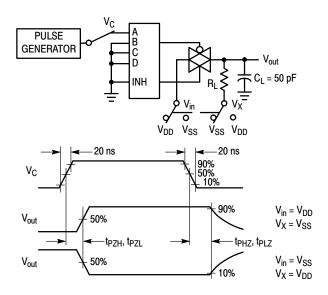


Figure 4. Turn-On and Delay Turn-Off Test Circuit and Waveforms

<sup>\*</sup>NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

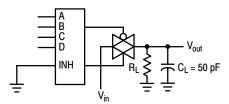


Figure 5. Bandwidth and Off-Channel Feedthrough Attenuation

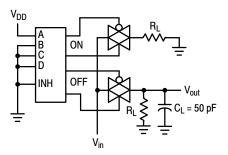


Figure 6. Channel Separation (Adjacent Channels Used for Setup)

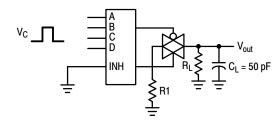


Figure 7. Crosstalk, Control to Common O/I

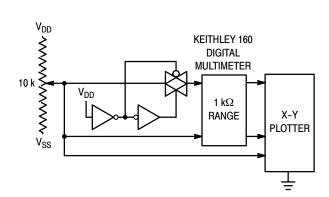


Figure 8. Channel Resistance (R<sub>ON</sub>) Test Circuit

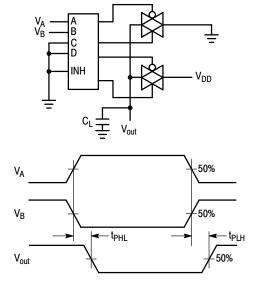


Figure 9. Propagation Delay, Any Pair of Address Inputs to Output

### TYPICAL RESISTANCE CHARACTERISTICS

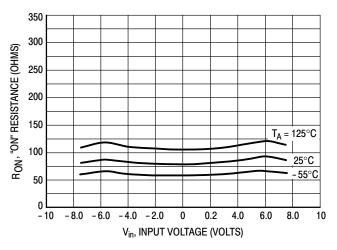


Figure 10.  $V_{DD}$  = 7.5 V,  $V_{SS}$  = - 7.5 V

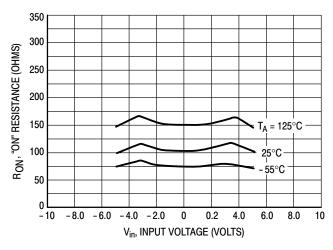


Figure 11.  $V_{DD}$  = 5.0 V,  $V_{SS}$  = - 5.0 V

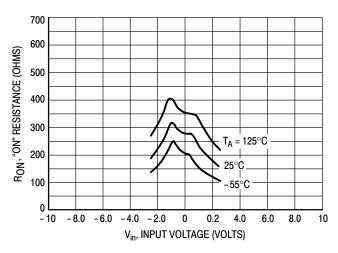


Figure 12.  $V_{DD}$  = 2.5 V,  $V_{SS}$  = - 2.5 V

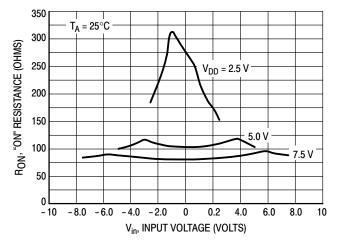


Figure 13. Comparison at 25°C,  $V_{DD} = -V_{SS}$ 

#### **APPLICATIONS INFORMATION**

Figure A illustrates use of the Analog Multiplexer / Demultiplexer. The 0-to-5 V Digital Control signal is used to directly control a 5  $V_{p-p}$  analog signal.

The digital control logic levels are determined by  $V_{DD}$  and  $V_{SS}$ . The  $V_{DD}$  voltage is the logic high voltage; the  $V_{SS}$  voltage is logic low. For the example.  $V_{DD}$  = + 5 V = logic high at the control inputs;  $V_{SS}$  = GND = 0 V = logic low.

The maximum analog signal level is determined by  $V_{DD}$  and  $V_{SS}$ . The analog voltage must swing neither higher than  $V_{DD}$  nor lower than  $V_{SS}$ . The example shows a 5  $V_{p-p}$ 

signal which allows no margin at either peak. If voltage transients above  $V_{DD}$  and/or below  $V_{SS}$  are anticipated on the analog channels, external diodes  $(D_x)$  are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The absolute maximum potential difference between  $V_{DD}$  and  $V_{SS}$  is 18.0 volts. Most parameters are specified up to 15 V which is the recommended maximum difference between  $V_{DD}$  and  $V_{SS}$ .

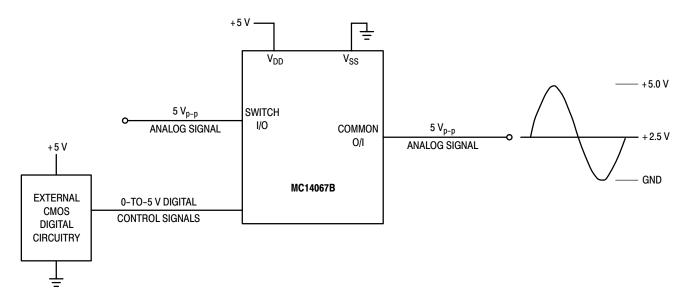


Figure A. Application Example

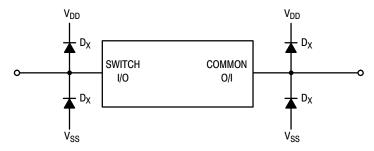
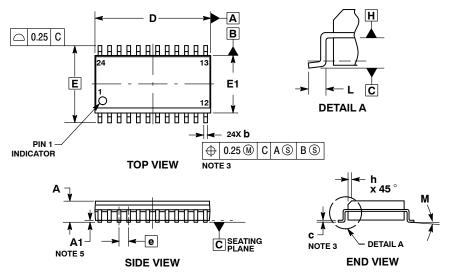


Figure B. External Germanium or Schottky Clipping Diodes

#### PACKAGE DIMENSIONS

#### SOIC-24 WB CASE 751E-04 **ISSUE F**

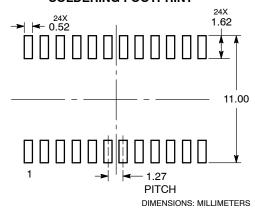


#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSIONS b AND c APPLY TO THE FLAT SEC-
- DIMENSIONS B AND CAPPLY TO THE FLAT SECTION OF THE LEAD AND ARE MEASURED BETWEEN 0.10 AND 0.25 FROM THE LEAD TIP. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT SUCCESS AS A DEPOLUTE AND THE PROPERTY OF THE PROP NOT EXCEED 0.15 mm PER SIDE. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
- A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

	MILLIMETERS				
DIM	MIN MAX				
Α	2.35	2.65			
A1	0.13 0.29				
ь	0.35	0.49			
C	0.23	0.32			
D	15.25 15.54				
E	10.30 BSC				
E1	7.40 7.60				
е	1.27 BSC				
h	0.25 0.75				
L	0.41 0.90				
М	0° 8°				

#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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